# Freescale Semiconductor Data Sheet: Technical Data

An Energy Efficient Solution by Freescale

### MC9S08QE128

80-LQFP Case 917A 14 mm<sup>2</sup>



64-LQFP Case 840F 10 mm<sup>2</sup> 44-LQFP Case 824D

Document Number: MC9S08QE128

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32-LQFP Case 873A 7 mm<sup>2</sup>

Eight deep FIFO for storing change-of-flow addresses and event-only data. Debug module supports both tag and force breakpoints.

- ADC 24-channel, 12-bit resolution; 2.5 μs conversion time; automatic compare function; 1.7 mV/°C temperature sensor; internal bandgap reference channel; operation in stop3; fully functional from 3.6V to 1.8V
- ACMPx Two analog comparators with selectable interrupt on rising, falling, or either edge of comparator output; compare option to fixed internal bandgap reference voltage; outputs can be optionally routed to TPM module; operation in stop3
- SCIx Two SCIs with full duplex non-return to zero (NRZ); LIN master extended break generation; LIN slave extended break detection; wake up on active edge
- SPIx—Two serial peripheral interfaces with Full-duplex or single-wire bidirectional; Double-buffered transmit and receive; MSB-first or LSB-first shifting
- IICx Two IICs with; Up to 100 kbps with maximum bus loading; Multi-master operation; Programmable slave address; Interrupt driven byte-by-byte data transfer; supports broadcast mode and 10 bit addressing
- TPMx One 6-channel and two 3-channel; Selectable input capture, output compare, or buffered edge- or center-aligned PWMs on each channel
- RTC 8-bit modulus counter with binary or decimal based prescaler; External clock source for precise time base, time-of-day, calendar or task scheduling functions; Free running on-chip low power oscillator (1 kHz) for cyclic wake-up without external components
- Input/Output
  - 70 GPIOs and 1 input-only and 1 output-only pin
  - 16 KBI interrupts with selectable polarity
  - Hysteresis and configurable pull-up device on all input pins; Configurable slew rate and drive strength on all output pins.
  - SET/CLR registers on 16 pins (PTC and PTE)

### MC9S08QE128 Series

Covers: MC9S08QE128, MC9S08QE96, MC9S08QE64

- 8-Bit HCS08 Central Processor Unit (CPU)
  - Up to 50.33-MHz HCS08 CPU above 2.4V, 40-MHz CPU above 2.1V, and 20-MHz CPU above 1.8V, across temperature range
  - HC08 instruction set with added BGND instruction
  - Support for up to 32 interrupt/reset sources
- On-Chip Memory
  - Flash read/program/erase over full operating voltage and temperature
  - Random-access memory (RAM)
  - Security circuitry to prevent unauthorized access to RAM and flash contents
- Power-Saving Modes
  - Two low power stop modes; reduced power wait mode
  - Peripheral clock enable register can disable clocks to unused modules, reducing currents; allows clocks to remain enabled to specific peripherals in stop3 mode
  - Very low power external oscillator can be used in stop3 mode to provide accurate clock to active peripherals
  - Very low power real time counter for use in run, wait, and stop modes with internal and external clock sources
  - 6 µs typical wake up time from stop modes
- Clock Source Options
  - Oscillator (XOSC) Loop-control Pierce oscillator;
     Crystal or ceramic resonator range of 31.25 kHz to 38.4 kHz or 1 MHz to 16 MHz
  - Internal Clock Source (ICS) FLL controlled by internal or external reference; precision trimming of internal reference allows 0.2% resolution and 2% deviation; supports CPU freq. from 2 to 50.33 MHz
- System Protection
  - Watchdog computer operating properly (COP) reset with option to run from dedicated 1-kHz internal clock source or bus clock
  - Low-voltage detection with reset or interrupt; selectable trip points
  - Illegal opcode detection with reset
  - Flash block protection
- Development Support
  - Single-wire background debug interface
  - Breakpoint capability to allow single breakpoint setting during in-circuit debugging (plus two more breakpoints)
  - On-chip in-circuit emulator (ICE) debug module containing two comparators and nine trigger modes.

Freescale reserves the right to change the detail specifications as may be required to permit improvements in the design of its products.

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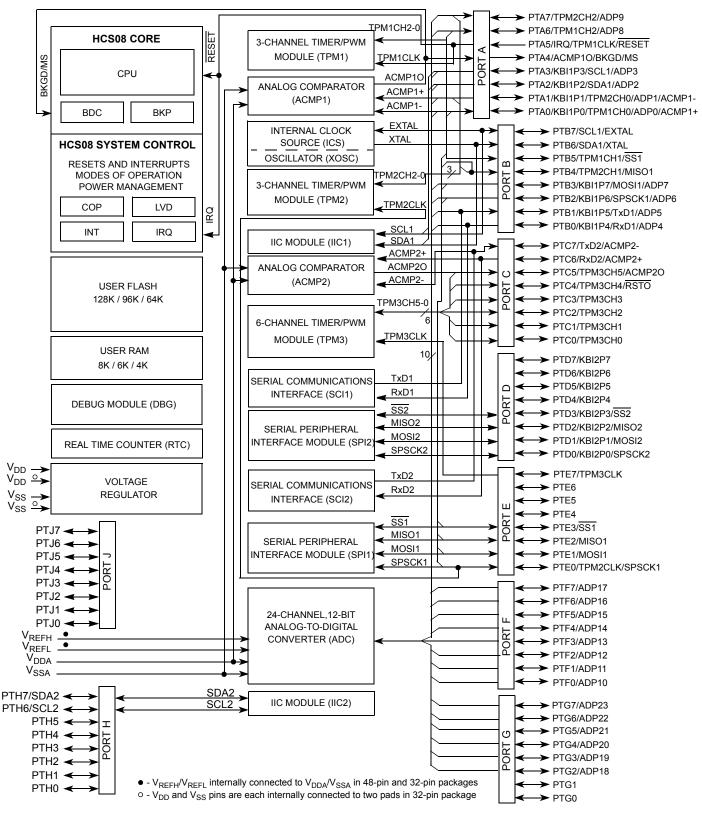


Figure 1. MC9S08QE128 Series Block Diagram

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# 1 MC9S08QE128 Series Comparison

The following table compares the various device derivatives available within the MC9S08QE128 series.

Table 1. MC9S08QE128 Series Features by MCU and Package

Feature	М	MC9S08QE128				MC9S08QE96				MC9S08QE64			
Flash size (bytes)	131072				98304				65536				
RAM size (bytes)	8064				6016					40	96		
Pin quantity	80	64	48	44	80	64	48	44	64	48	44	32	
ACMP1			•	•		ye	es		•		•	•	
ACMP2						уe	es						
ADC channels	24	22	10	10	24	22	10	10	22	10	10	10	
DBG						ye	es						
ICS						уe	es						
IIC1	yes												
IIC2	yes	yes	no	no	yes	yes	no	no	yes	no	no	no	
IRQ						y€	es						
KBI	16	16	16	16	16	16	16	16	16	16	16	12	
Port I/O <sup>1</sup>	70	54	38	34	70	54	38	34	54	38	34	26	
RTC						уe	es						
SCI1						y€	es						
SCI2						уe	es						
SPI1						уe	es						
SPI2						ye	es						
TPM1 channels	3												
TPM2 channels	3												
TPM3 channels	6												
XOSC						ye	es						

Port I/O count does not include the input only PTA5/IRQ/TPM1CLK/RESET or the output only PTA4/ACMP1O/BKGD/MS.

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### 2 Pin Assignments

This section describes the pin assignments for the available packages. See Table 2 for pin availability by package pin-count.

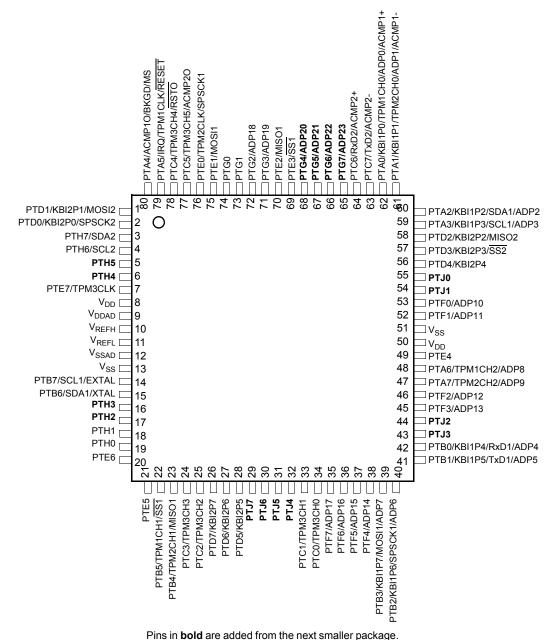


Figure 2. Pin Assignments in 80-Pin LQFP

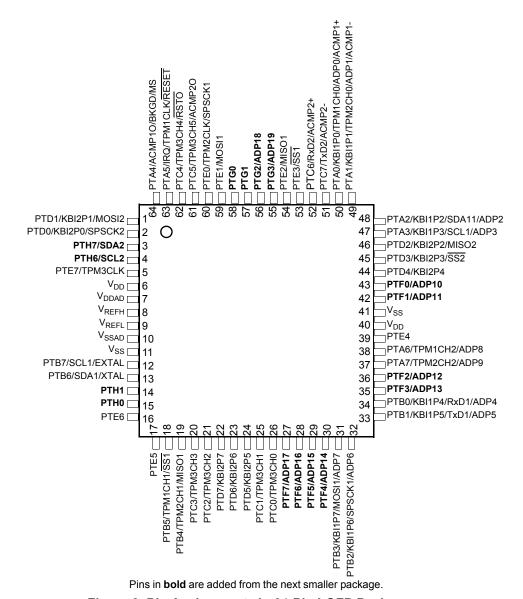


Figure 3. Pin Assignments in 64-Pin LQFP Package

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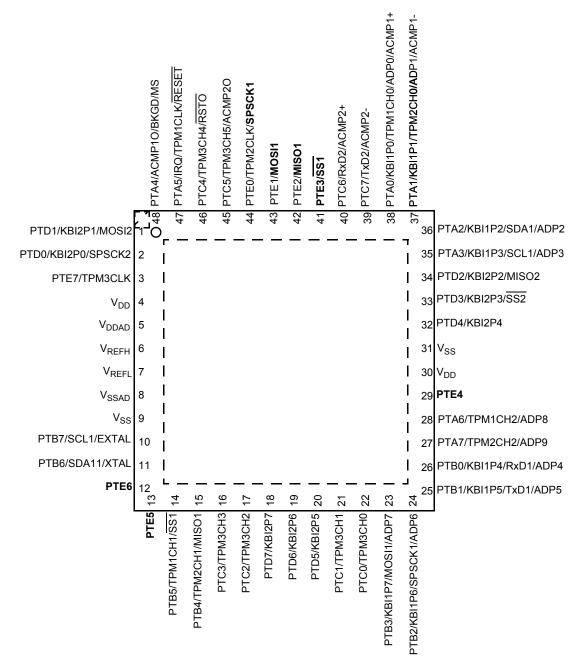


Figure 4. Pin Assignments in 48-Pin QFN Package

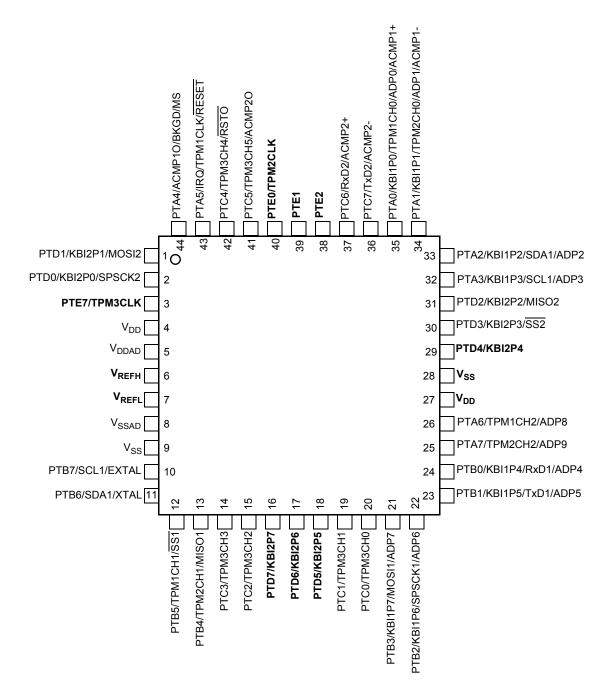


Figure 5. Pin Assignments in 44-Pin LQFP Package

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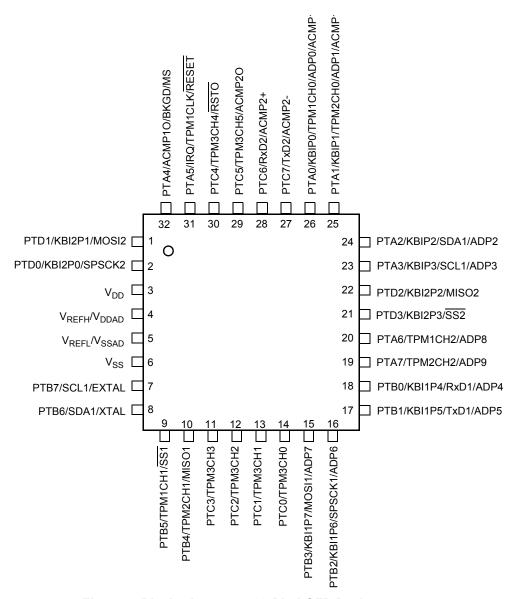


Figure 6. Pin Assignments 32-Pin LQFP Package

#### **Pin Assignments**

Table 2. MC9S08QE128 Series Pin Assignment by Package and Pin Count

	Pir	n Num	ber		Lowest	←	Priority	<b>─</b>	Highest
80	64	48	44	32	Port Pin	Alt 1	Alt 2	Alt 3	Alt 4
1	1	1	1	1	PTD1	KBI2P1	MOSI2		
2	2	2	2	2	PTD0	KBI2P0	SPSCK2		
3	3	_	_	_	PTH7	SDA2			
4	4	_	_	_	PTH6	SCL2			
5	_	_	_	_	PTH5				
6	_	_	_	_	PTH4				
7	5	3	3	_	PTE7	TPM3CLK			
8	6	4	4	3					$V_{DD}$
9	7	5	5	4					$V_{DDA}$
10	8	6	6	_					V <sub>REFH</sub>
11	9	7	7	_					V <sub>REFL</sub>
12	10	8	8	5					V <sub>SSA</sub>
13	11	9	9	6					V <sub>SS</sub>
14	12	10	10	7	PTB7	SCL1			EXTAL
15	13	11	11	8	PTB6	SDA1			XTAL
16	_	_	_	_	PTH3				
17	_		_	_	PTH2				
18	14	_	_	_	PTH1				
19	15	_	_	_	PTH0				
20	16	12	_	_	PTE6				
21	17	13		_	PTE5				
22	18	14	12	9	PTB5	TPM1CH1	SS1		
23	19	15	13	10	PTB4	TPM2CH1	MISO1		
24	20	16	14	11	PTC3	TPM3CH3			
25	21	17	15	12	PTC2	TPM3CH2			
26	22	18	16	_	PTD7	KBI2P7			
27	23	19	17	_	PTD6	KBI2P6			
28	24	20	18	1	PTD5	KBI2P5			
29	_	_	_	_	PTJ7				
30	_	_	_	_	PTJ6				
31	_			-	PTJ5				
32	_	_	_	_	PTJ4				
33	25	21	19	13	PTC1	TPM3CH1			
34	26	22	20	14	PTC0	TPM3CH0			
35	27	_	_	_	PTF7				ADP17
36	28	_	_	_	PTF6				ADP16
37	29	_	_	_	PTF5				ADP15
38	30	_	_	_	PTF4				ADP14
39	31	23	21	15	PTB3	KBI1P7	MOSI1		ADP7
40	32	24	22	16	PTB2	KBI1P6	SPSCK1		ADP6

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Table 2. MC9S08QE128 Series Pin Assignment by Package and Pin Count (continued)

	Pir	n Num	ber		Lowest	←	Priority	$\longrightarrow$	Highest
80	64	48	44	32	Port Pin	Alt 1	Alt 2	Alt 3	Alt 4
41	33	25	23	17	PTB1	KBI1P5	TxD1		ADP5
42	34	26	24	18	PTB0	KBI1P4	RxD1		ADP4
43	_		_	_	PTJ3				
44	_	_	_	_	PTJ2				
45	35	_	_	_	PTF3				ADP13
46	36	_	_	_	PTF2				ADP12
47	37	27	25	19	PTA7	TPM2CH2			ADP9
48	38	28	26	20	PTA6	TPM1CH2			ADP8
49	39	29	_	_	PTE4				
50	40	30	27						$V_{DD}$
51	41	31	28	_					V <sub>SS</sub>
52	42	_			PTF1				ADP11
53	43	_	_	_	PTF0				ADP10
54	_	_			PTJ1				
55	_	_			PTJ0				
56	44	32	29		PTD4	KBI2P4			
57	45	33	30	21	PTD3	KBI2P3	SS2		
58	46	34	31	22	PTD2	KBI2P2	MISO2		
59	47	35	32	23	PTA3	KBI1P3	SCL1		ADP3
60	48	36	33	24	PTA2	KBI1P2	SDA1		ADP2
61	49	37	34	25	PTA1	KBI1P1	TPM2CH0	ADP1	ACMP1-
62	50	38	35	26	PTA0	KBI1P0	TPM1CH0	ADP0	ACMP1+
63	51	39	36	27	PTC7	TxD2			ACMP2-
64	52	40	37	28	PTC6	RxD2			ACMP2+
65	_	_	—	_	PTG7				ADP23
66	_	_	—	_	PTG6				ADP22
67	_	_	_	_	PTG5				ADP21
68	_	_	_	_	PTG4				ADP20
69	53	41	_	_	PTE3	SS1			
70	54	42	38	_	PTE2	MISO1			
71	55	_			PTG3				ADP19
72	56	_			PTG2				ADP18
73	57	_			PTG1				
74	58	_			PTG0				
75	59	43	39	1	PTE1	MOSI1			
76	60	44	40		PTE0	TPM2CLK	SPSCK1		
77	61	45	41	29	PTC5	TPM3CH5			ACMP2O
78	62	46	42	30	PTC4	TPM3CH4	RSTO		
79	63	47	43	31	PTA5	IRQ	TPM1CLK	RESET	
80	64	48	44	32	PTA4	ACMP10	BKGD	MS	

#### 3.1 Introduction

This section contains electrical and timing specifications for the MC9S08QE128 series of microcontrollers available at the time of publication.

#### 3.2 Parameter Classification

The electrical parameters shown in this supplement are guaranteed by various methods. To give the customer a better understanding the following classification is used and the parameters are tagged accordingly in the tables where appropriate:

**Table 3. Parameter Classifications** 

Р	Those parameters are guaranteed during production testing on each individual device.
С	Those parameters are achieved by the design characterization by measuring a statistically relevant sample size across process variations.
Т	Those parameters are achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted. All values shown in the typical column are within this category.
D	Those parameters are derived mainly from simulations.

#### NOTE

The classification is shown in the column labeled "C" in the parameter tables where appropriate.

### 3.3 Absolute Maximum Ratings

Absolute maximum ratings are stress ratings only, and functional operation at the maxima is not guaranteed. Stress beyond the limits specified in Table 4 may affect device reliability or cause permanent damage to the device. For functional operating conditions, refer to the remaining tables in this section.

This device contains circuitry protecting against damage due to high static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for instance, either  $V_{SS}$  or  $V_{DD}$ ) or the programmable pull-up resistor associated with the pin is enabled.

Rating	Symbol	Value	Unit
Supply voltage	$V_{DD}$	-0.3 to +3.8	V
Maximum current into V <sub>DD</sub>	I <sub>DD</sub>	120	mA
Digital input voltage	V <sub>In</sub>	$-0.3$ to $V_{DD} + 0.3$	V
Instantaneous maximum current Single pin limit (applies to all port pins) <sup>1, 2, 3</sup>	I <sub>D</sub>	± 25	mA
Storage temperature range	T <sub>stg</sub>	-55 to 150	°C

Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive (V<sub>DD</sub>) and negative (V<sub>SS</sub>) clamp voltages, then use the larger of the two resistance values.

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 $<sup>^{2}</sup>$  All functional non-supply pins are internally clamped to  $V_{SS}$  and  $V_{DD}$ .

Power supply must maintain regulation within operating  $V_{DD}$  range during instantaneous and operating maximum current conditions. If positive injection current ( $V_{In} > V_{DD}$ ) is greater than  $I_{DD}$ , the injection current may flow out of  $V_{DD}$  and could result in external power supply going out of regulation. Ensure external  $V_{DD}$  load will shunt current greater than maximum injection current. This will be the greatest risk when the MCU is not consuming power. Examples are: if no system clock is present, or if the clock rate is very low (which would reduce overall power consumption).

#### 3.4 Thermal Characteristics

This section provides information about operating temperature range, power dissipation, and package thermal resistance. Power dissipation on I/O pins is usually small compared to the power dissipation in on-chip logic and voltage regulator circuits, and it is user-determined rather than being controlled by the MCU design. To take  $P_{\rm I/O}$  into account in power calculations, determine the difference between actual pin voltage and  $V_{\rm SS}$  or  $V_{\rm DD}$  and multiply by the pin current for each I/O pin. Except in cases of unusually high pin current (heavy loads), the difference between pin voltage and  $V_{\rm SS}$  or  $V_{\rm DD}$  will be very small.

Rating **Symbol** Value Unit Operating temperature range (packaged) -40 to 85 °C  $T_A$ Maximum junction temperature 95 ٥С  $T_{JM}$ Thermal resistance Single-layer board 32-pin LQFP 82 °C/W 44-pin LQFP  $\theta_{\mathsf{JA}}$ 68 48-pin QFN 81 64-pin LQFP 69  $\theta_{\text{JA}}$ °C/W 80-pin LQFP 60 Thermal resistance Four-layer board 32-pin LQFP 54 44-pin LQFP °C/W 46  $\theta_{\mathsf{JA}}$ 48-pin QFN 26 64-pin LQFP 50 °C/W  $\theta_{JA}$ 47 80-pin LQFP

**Table 5. Thermal Characteristics** 

The average chip-junction temperature  $(T_I)$  in °C can be obtained from:

$$T_{J} = T_{A} + (P_{D} \times \theta_{JA})$$
 Eqn. 1

where:

 $T_A = Ambient temperature, °C$ 

 $\theta_{JA}$  = Package thermal resistance, junction-to-ambient, °C/W

 $P_D = P_{int} + P_{I/O}$ 

 $P_{int} = I_{DD} \times V_{DD}$ , Watts — chip internal power

 $P_{I/O}$  = Power dissipation on input and output pins — user determined

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For most applications,  $P_{I/O} \ll P_{int}$  and can be neglected. An approximate relationship between  $P_D$  and  $T_J$  (if  $P_{I/O}$  is neglected) is:

$$P_D = K \div (T_J + 273^{\circ}C)$$
 Eqn. 2

Solving Equation 1 and Equation 2 for K gives:

$$K = P_D \times (T_\Delta + 273^{\circ}C) + \theta_{A\Delta} \times (P_D)^2$$
 Eqn. 3

where K is a constant pertaining to the particular part. K can be determined from equation 3 by measuring  $P_D$  (at equilibrium) for a known  $T_A$ . Using this value of K, the values of  $P_D$  and  $T_J$  can be obtained by solving Equation 1 and Equation 2 iteratively for any value of  $T_A$ .

### 3.5 ESD Protection and Latch-Up Immunity

Although damage from electrostatic discharge (ESD) is much less common on these devices than on early CMOS circuits, normal handling precautions should be used to avoid exposure to static discharge. Qualification tests are performed to ensure that these devices can withstand exposure to reasonable levels of static without suffering any permanent damage.

All ESD testing is in conformity with AEC-Q100 Stress Test Qualification for Automotive Grade Integrated Circuits. During the device qualification ESD stresses were performed for the human body model (HBM), the machine model (MM) and the charge device model (CDM).

A device is defined as a failure if after exposure to ESD pulses the device no longer meets the device specification. Complete DC parametric and functional testing is performed per the applicable device specification at room temperature followed by hot temperature, unless specified otherwise in the device specification.

Model	Description	Symbol	Value	Unit
	Series resistance	R1	1500	Ω
Human Body	Storage capacitance	С	100	pF
,	Number of pulses per pin	_	3	
	Series resistance	R1	0	Ω
Machine	Storage capacitance	С	200	pF
	Number of pulses per pin	_	3	
Latch-up	Minimum input voltage limit		<b>- 2.5</b>	V
Lateri-up	Maximum input voltage limit		7.5	V

Table 6. ESD and Latch-up Test Conditions

Table 7. ESD and Latch-Up Protection Characteristics

No.	Rating <sup>1</sup>	Symbol	Min	Max	Unit
1	Human body model (HBM)	V <sub>HBM</sub>	± 2000	_	V
2	Machine model (MM)	V <sub>MM</sub>	± 200	_	V
3	Charge device model (CDM)	V <sub>CDM</sub>	± 500	_	V
4	Latch-up current at T <sub>A</sub> = 85°C	I <sub>LAT</sub>	± 100	_	mA

Parameter is achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted.

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#### 3.6 DC Characteristics

This section includes information about power supply requirements and I/O pin characteristics.

**Table 8. DC Characteristics** 

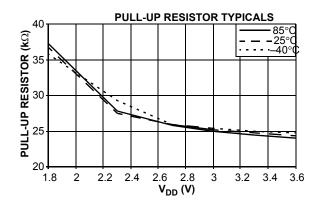
Num	С	Cha	aracteristic	Symbol	Condition	Min	Typ <sup>1</sup>	Max	Unit	
1		Operating Voltage	9			1.8 <sup>2</sup>		3.6	V	
	С	Output high voltage	All I/O pins, low-drive strength		1.8 V, I <sub>Load</sub> = –2 mA	V <sub>DD</sub> – 0.5	_	_		
2	Р		All I/O pins,	V <sub>OH</sub>	$2.7 \text{ V}, I_{Load} = -10 \text{ mA}$	V <sub>DD</sub> – 0.5	_	_	V	
	Т		high-drive strength		2.3 V, I <sub>Load</sub> = -6 mA	V <sub>DD</sub> – 0.5	_	_		
	С				1.8V, $I_{Load} = -3 \text{ mA}$	V <sub>DD</sub> – 0.5	_	_		
3	D	Output high current	Max total I <sub>OH</sub> for all ports	I <sub>OHT</sub>		ı	l	100	mA	
	С	Output low voltage	All I/O pins, low-drive strength		1.8 V, I <sub>Load</sub> = 2 mA		_	0.5		
4	Р		All I/O pins,	$V_{OL}$	2.7 V, I <sub>Load</sub> = 10 mA	_	_	0.5	٧	
	Т		high-drive strength		2.3 V, I <sub>Load</sub> = 6 mA	_	_	0.5		
	С				1.8 V, I <sub>Load</sub> = 3 mA	_	_	0.5		
5	D	Output low current	Max total I <sub>OL</sub> for all ports	I <sub>OLT</sub>		_	_	100	mA	
6	Р	Input high	all digital inputs	V	V <sub>DD</sub> > 2.7 V	0.70 x V <sub>DD</sub>	_	_		
0	С	voltage		V <sub>IH</sub>	V <sub>DD</sub> > 1.8 V	0.85 x V <sub>DD</sub>	_	_	V	
7	Р	Input low voltage	all digital inputs	V <sub>IL</sub>	V <sub>DD</sub> > 2.7 V	_	_	0.35 x V <sub>DD</sub>	V	
,	С			VIL.	V <sub>DD</sub> >1.8 V	_	_	0.30 x V <sub>DD</sub>		
8	С	Input hysteresis	all digital inputs	V <sub>hys</sub>		0.06 x V <sub>DD</sub>	_	_	mV	
9	Р	Input leakage current	all input only pins (Per pin)	I <sub>In </sub>	$V_{In} = V_{DD}$ or $V_{SS}$		1	1	μА	
10	Р	Hi-Z (off-state) leakage current	all input/output (per pin)	I <sub>OZ </sub>	$V_{In} = V_{DD}$ or $V_{SS}$	_	_	1	μА	
11	Р	Pull-up resistors	all digital inputs, when enabled	R <sub>PU</sub>		17.5	_	52.5	kΩ	
		DC injection	Single pin limit			-0.2	_	0.2	mA	
12	D	current <sup>3, 4, 5</sup>	Total MCU limit, includes sum of all stressed pins	I <sub>IC</sub>	$V_{IN} < V_{SS}, V_{IN} > V_{DD}$	-5	_	5	mA	
13	С	Input Capacitance, all pins		C <sub>In</sub>		_		8	pF	
14	С	RAM retention voltage		V <sub>RAM</sub>		_	0.6	1.0	V	
15	С	POR re-arm volta	ge <sup>6</sup>	V <sub>POR</sub>		0.9	1.4	1.79	V	
16	D	POR re-arm time		t <sub>POR</sub>		10	_	_	μS	
17	Р	Low-voltage deter high range <sup>7</sup>	ction threshold —	V <sub>LVDH</sub> <sup>8</sup>	V <sub>DD</sub> falling V <sub>DD</sub> rising	2.11 2.16	2.16 2.21	2.22 2.27	V	

**Table 8. DC Characteristics (continued)** 

Num	С	Characteristic	Symbol	Condition	Min	Typ <sup>1</sup>	Max	Unit
18	Р	Low-voltage detection threshold — low range <sup>7</sup>	V <sub>LVDL</sub>	V <sub>DD</sub> falling V <sub>DD</sub> rising	1.80 1.86	1.82 1.90	1.91 1.99	V
19	Р	Low-voltage warning threshold — high range <sup>7</sup>	V <sub>LVWH</sub>	V <sub>DD</sub> falling V <sub>DD</sub> rising	2.36 2.36	2.46 2.46	2.56 2.56	V
20	Р	Low-voltage warning threshold — low range <sup>7</sup>	V <sub>LVWL</sub>	V <sub>DD</sub> falling V <sub>DD</sub> rising	2.11 2.16	2.16 2.21	2.22 2.27	V
21	С	Low-voltage inhibit reset/recover hysteresis <sup>7</sup>	V <sub>hys</sub>		_	50	_	mV
22	Р	Bandgap Voltage Reference <sup>9</sup>	$V_{BG}$		1.15	1.17	1.18	V

<sup>&</sup>lt;sup>1</sup> Typical values are measured at 25°C. Characterized, not tested

- <sup>6</sup> Maximum is highest voltage that POR is guaranteed.
- <sup>7</sup> Low voltage detection and warning limits measured at 1 MHz bus frequency.
- <sup>8</sup> Run at 1 MHz bus frequency
- <sup>9</sup> Factory trimmed at V<sub>DD</sub> = 3.0 V, Temp = 25°C



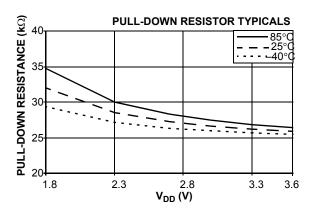


Figure 7. Pull-up and Pull-down Typical Resistor Values

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<sup>&</sup>lt;sup>2</sup> As the supply voltage rises, the LVD circuit will hold the MCU in reset until the supply has risen above V<sub>LVDL</sub>.

 $<sup>^3</sup>$  All functional non-supply pins are internally clamped to  $V_{SS}$  and  $V_{DD}$ .

<sup>&</sup>lt;sup>4</sup> Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive and negative clamp voltages, then use the larger of the two values.

Power supply must maintain regulation within operating V<sub>DD</sub> range during instantaneous and operating maximum current conditions. If positive injection current (V<sub>In</sub> > V<sub>DD</sub>) is greater than I<sub>DD</sub>, the injection current may flow out of V<sub>DD</sub> and could result in external power supply going out of regulation. Ensure external V<sub>DD</sub> load will shunt current greater than maximum injection current. This will be the greatest risk when the MCU is not consuming power. Examples are: if no system clock is present, or if clock rate is very low (which would reduce overall power consumption).

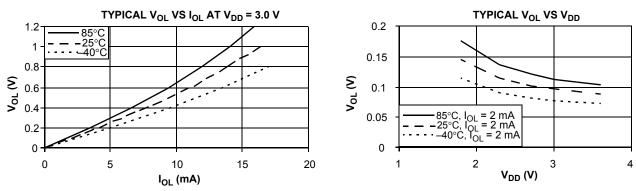


Figure 8. Typical Low-Side Driver (Sink) Characteristics — Low Drive (PTxDSn = 0)

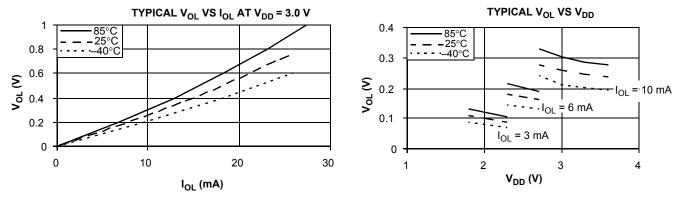


Figure 9. Typical Low-Side Driver (Sink) Characteristics — High Drive (PTxDSn = 1)

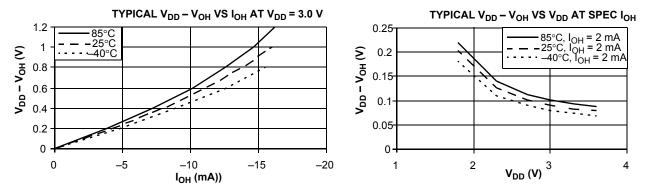


Figure 10. Typical High-Side (Source) Characteristics — Low Drive (PTxDSn = 0)

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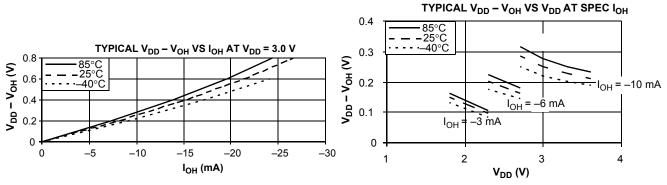


Figure 11. Typical High-Side (Source) Characteristics — High Drive (PTxDSn = 1)

### 3.7 Supply Current Characteristics

This section includes information about power supply current in various operating modes.

**Table 9. Supply Current Characteristics** 

Num	С	Parameter	Symbol	Bus Freq	V <sub>DD</sub> (V)	Typ <sup>1</sup>	Max	Unit	Temp (°C)
	Р	Run supply current		25.165 MHz		16	18		-40 to 25
	Р	FEI mode, all modules on		23. 103 WII 12		16	20		85
1	Т		$RI_DD$	20 MHz	3	14.4	_	mA	
	Т			8 MHz		6.5	_		–40 to 85
	Т			1 MHz		1.4	1		
	С	Run supply current	RI <sub>DD</sub>	25.165 MHz	3	11.5	12.3		
2	Т	FEI mode, all modules off		20 MHz		9.5		mA	-40 to 85
_	Т		טטייי	8 MHz	Ü	4.6		1112.	10 10 00
	Т			1 MHz		1.0	_		
3	Т	Run supply current LPS=0, all modules off	RI <sub>DD</sub>	16 kHz FBILP	3	152	_	μА	-40 to 85
	Т		IVIDD .	16 kHz FBELP	Ŭ	115		pu (	40 10 00
	Т	Run supply current				04.0	_		0 to 70
4	ı	LPS=1, all modules off, running from Flash	RI <sub>DD</sub>	16 kHz	3	21.9		μА	–40 to 85
	Т	Run supply current	טטייי	FBELP	ŭ	7.3	_	μυτ	0 to 70
	'	LPS=1, all modules off, running from RAM				7.3	_		-40 to 85
	С	Wait mode supply current		25.165 MHz		5.74	6		
5	Т	FEI mode, all modules off	WI <sub>DD</sub>	20 MHz	3	4.57	_	mA	40 to 85
	Т			8 MHz		2	_		40 10 00
	Т			1 MHz		0.73	_		

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**Table 9. Supply Current Characteristics (continued)** 

Num	С	Parameter	Symbol	Bus Freq	V <sub>DD</sub> (V)	Typ <sup>1</sup>	Max	Unit	Temp (°C)
	Р	Stop2 mode supply current				0.35	0.6		-40 to 25
	С		S2I <sub>DD</sub>	n/a	3	0.98	2.0		70
6	Р					2.5	7.5	- - μΑ -	85
	С				2	0.25	0.5		-40 to 25
	С					1.4	1.9		70
	С					1.91	6.5		85
	Р	Stop3 mode supply current No clocks active				0.45	1.0		-40 to 25
	С				3	1.99	4.2		70
7	Р		<b>S</b> 31	n/a		5.0	15.0	μΑ	85
'	С		S3I <sub>DD</sub>	II/a		0.35	0.7	μΛ	-40 to 25
-	С				2	2.9	3.9		70
	С					3.77	13.2		85

Data in Typical column was characterized at 3.0 V, 25°C or is typical recommended value.

**Table 10. Stop Mode Adders** 

Num	С	Parameter	Condition		Tempera	ture (°C)		Units
Nulli		Parameter	Condition	-40	25	70	85	Ullits
1	Т	LPO		50	75	100	150	nA
2	Т	ERREFSTEN	RANGE = HGO = 0	1000	1000	1100	1500	nA
3	Т	IREFSTEN <sup>1</sup>		63	70	77	81	uA
4	Т	RTC	does not include clock source current	50	75	100	150	nA
5	Т	LVD <sup>1</sup>	LVDSE = 1	90	100	110	115	uA
6	Т	ACMP <sup>1</sup>	not using the bandgap (BGBE = 0)	18	20	22	23	uA
7	Т	ADC <sup>1</sup>	ADLPC = ADLSMP = 1 not using the bandgap (BGBE = 0)	95	106	114	120	uA

<sup>&</sup>lt;sup>1</sup> Not available in stop2 mode.

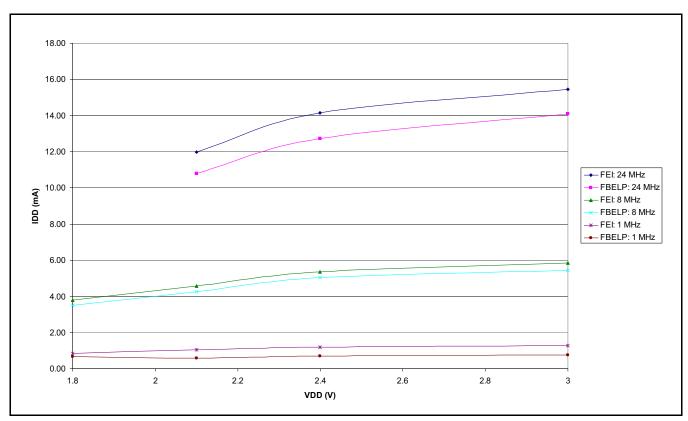


Figure 12. Typical Run  $I_{DD}$  for FBE and FEI,  $I_{DD}$  vs.  $V_{DD}$  (ADC off, All Other Modules Enabled)

### 3.8 External Oscillator (XOSC) Characteristics

Reference Figure 13 and Figure 14 for crystal or resonator circuits.

Table 11. XOSC and ICS Specifications (Temperature Range = -40 to 85°C Ambient)

Num	С	Characteristic	Symbol	Min	Typ <sup>1</sup>	Max	Unit	
1	С	Oscillator crystal or resonator (EREFS = 1, ERCLKEN = 1) Low range (RANGE = 0) High range (RANGE = 1), high gain (HGO = 1) High range (RANGE = 1), low power (HGO = 0)	f <sub>lo</sub> f <sub>hi</sub> f <sub>hi</sub>	32 1 1	_ _ _	38.4 16 8	kHz MHz MHz	
2	2 D Load capacitors 2 D Low range (RANGE=0), low power (HGO=0) Other oscillator settings				See Note <sup>2</sup> See Note <sup>3</sup>			
3	D	Feedback resistor Low range, low power (RANGE=0, HGO=0) <sup>2</sup> Low range, High Gain (RANGE=0, HGO=1) High range (RANGE=1, HGO=X)	R <sub>F</sub>	_ _ _	 10 1		МΩ	
4	D	Series resistor — Low range, low power (RANGE = 0, HGO = 0) <sup>2</sup> Low range, high gain (RANGE = 0, HGO = 1) High range, low power (RANGE = 1, HGO = 0) High range, high gain (RANGE = 1, HGO = 1) ≥ 8 MHz 4 MHz 1 MHz	R <sub>S</sub>	_ _ _ _	 0 100 0 0		kΩ	
5	С	Crystal start-up time <sup>4</sup> Low range, low power Low range, high power High range, low power High range, high power	t CSTL t CSTH	_ _ _ _	200 400 5 15	_ _ _ _	ms	
6	D	Square wave input clock frequency (EREFS = 0, ERCLKEN = 1) FEE or FBE mode FBELP mode	f <sub>extal</sub>	0.03125 0	_ _	40.0 50.33	MHz MHz	

<sup>1</sup> Data in Typical column was characterized at 3.0 V, 25°C or is typical recommended value.

<sup>&</sup>lt;sup>2</sup> Load capacitors  $(C_1, C_2)$ , feedback resistor  $(R_F)$  and series resistor  $(R_S)$  are incorporated internally when RANGE=HGO=0.

<sup>&</sup>lt;sup>3</sup> See crystal or resonator manufacturer's recommendation.

<sup>&</sup>lt;sup>4</sup> Proper PC board layout procedures must be followed to achieve specifications.

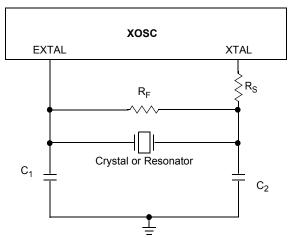


Figure 13. Typical Crystal or Resonator Circuit: High Range and Low Range/High Gain

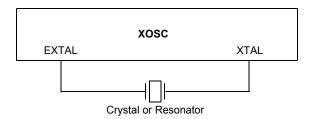


Figure 14. Typical Crystal or Resonator Circuit: Low Range/Low Gain

### 3.9 Internal Clock Source (ICS) Characteristics

Table 12. ICS Frequency Specifications (Temperature Range = -40 to 85°C Ambient)

Num	С	Charac	teristic	Symbol	Min	Typ <sup>1</sup>	Max	Unit
1	Р		Average internal reference frequency — factory trimmed at V <sub>DD</sub> = 3.6 V and temperature = 25°C		_	32.768	_	kHz
2	Р	Internal reference frequency — L	iser trimmed	f <sub>int_ut</sub>	31.25	_	39.06	kHz
3	Т	Internal reference start-up time		t <sub>IRST</sub>	_	60	100	μS
	Р	D00 t t f	Low range (DRS=00)		16	_	20	
4	DCO output frequency range — trimmed <sup>2</sup>	Mid range (DRS=01)	f <sub>dco_u</sub>	32	_	40	MHz	
	Р		High range (DRS=10)		48	_	60	
	Р	DCO output frequency <sup>2</sup>	Low range (DRS=00)		_	19.92	_	
5	Р	Reference = 32768 Hz and	Mid range (DRS=01)	f <sub>dco_DMX32</sub>	_	39.85	_	MHz
	Р	DMX32 = 1	High range (DRS=10)		_	59.77	_	
6	С	Resolution of trimmed DCO output frequency at fixed voltage and temperature (using FTRIM)		$\Delta f_{dco\_res\_t}$	_	± 0.1	± 0.2	%f <sub>dco</sub>
7	С	Resolution of trimmed DCO outp temperature (not using FTRIM)	ut frequency at fixed voltage and	$\Delta f_{dco\_res\_t}$	_	± 0.2	± 0.4	%f <sub>dco</sub>

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Table 12. ICS Frequency Specifications (Temperature Range = -40 to 85°C Ambient) (continued)

Num	С	Characteristic	Symbol	Min	Typ <sup>1</sup>	Max	Unit
8	С	Total deviation of trimmed DCO output frequency over voltage and temperature	Δf <sub>dco_t</sub>	_	+ 0.5 -1.0	± 2	%f <sub>dco</sub>
9	С	Total deviation of trimmed DCO output frequency over fixed voltage and temperature range of 0°C to 70 °C		_	± 0.5	± 1	%f <sub>dco</sub>
10	С	FLL acquisition time <sup>3</sup>	t <sub>Acquire</sub>	_	_	1	ms
11	С	Long term jitter of DCO output clock (averaged over 2-ms interval) <sup>4</sup>	C <sub>Jitter</sub>		0.02	0.2	%f <sub>dco</sub>

<sup>&</sup>lt;sup>1</sup> Data in Typical column was characterized at 3.0 V, 25°C or is typical recommended value.

Jitter is the average deviation from the programmed frequency measured over the specified interval at maximum f<sub>Bus</sub>. Measurements are made with the device powered by filtered supplies and clocked by a stable external clock signal. Noise injected into the FLL circuitry via V<sub>DD</sub> and V<sub>SS</sub> and variation in crystal oscillator frequency increase the C<sub>Jitter</sub> percentage for a given interval.

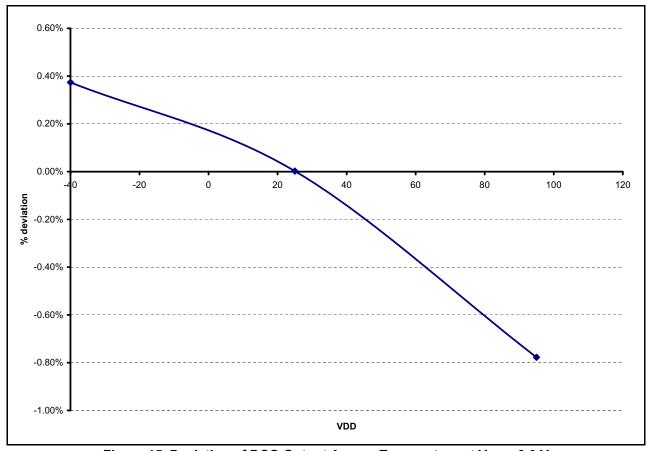


Figure 15. Deviation of DCO Output Across Temperature at V<sub>DD</sub> = 3.0 V

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<sup>&</sup>lt;sup>2</sup> The resulting bus clock frequency should not exceed the maximum specified bus clock frequency of the device.

<sup>&</sup>lt;sup>3</sup> This specification applies to any time the FLL reference source or reference divider is changed, trim value changed or changing from FLL disabled (FBELP, FBILP) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.

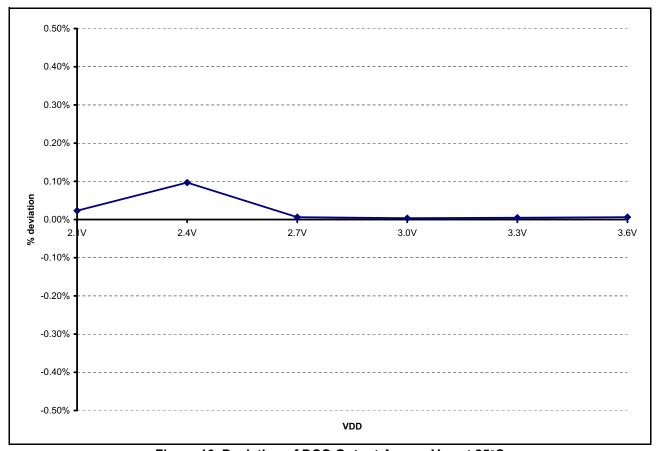


Figure 16. Deviation of DCO Output Across V<sub>DD</sub> at 25°C

#### 3.10 AC Characteristics

This section describes timing characteristics for each peripheral system.

### 3.10.1 Control Timing

**Table 13. Control Timing** 

Num	С	Rating	Symbol	Min	Typ <sup>1</sup>	Max	Unit
1	D	Bus frequency ( $t_{cyc}$ = 1/ $f_{Bus}$ ) $V_{DD} \ge 1.8V$ $V_{DD} > 2.1V$ $V_{DD} > 2.4V$	f <sub>Bus</sub>	dc	_ _ _	10 20 25.165	MHz
2	D	Internal low power oscillator period	t <sub>LPO</sub>	700	_	1300	μS
3	D	External reset pulse width <sup>2</sup>	t <sub>extrst</sub>	100	_	_	ns
4	D	Reset low drive	t <sub>rstdrv</sub>	34 x t <sub>cyc</sub>	_	_	ns
5	D	BKGD/MS setup time after issuing background debug force reset to enter user or BDM modes	t <sub>MSSU</sub>	500	_	_	ns
6	D	BKGD/MS hold time after issuing background debug force reset to enter user or BDM modes <sup>3</sup>	t <sub>MSH</sub>	100	_	_	μS

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Table 13	Control	Timing	(continued)
I abic io.		HILLING	(COIILIIIGEA)

Num	С	Rating	Symbol	Min	Typ <sup>1</sup>	Max	Unit
7	D	IRQ pulse width Asynchronous path <sup>2</sup> Synchronous path <sup>4</sup>	t <sub>ILIH,</sub> t <sub>IHIL</sub>	100 1.5 x t <sub>cyc</sub>	_ _	_	ns
8	D	Keyboard interrupt pulse width Asynchronous path <sup>2</sup> Synchronous path <sup>4</sup>	t <sub>ILIH</sub> , t <sub>IHIL</sub>	100 1.5 x t <sub>cyc</sub>	_ _	_	ns
9	С	Port rise and fall time — Low output drive (PTxDS = 0) (load = 50 pF) <sup>5</sup> Slew rate control disabled (PTxSE = 0) Slew rate control enabled (PTxSE = 1)	t <sub>Rise</sub> , t <sub>Fall</sub>		8 31	_	ns
		Port rise and fall time — High output drive (PTxDS = 1) (load = 50 pF) Slew rate control disabled (PTxSE = 0) Slew rate control enabled (PTxSE = 1)	t <sub>Rise</sub> , t <sub>Fall</sub>	_	7 24		ns
10		Voltage regulator recovery time	t <sub>VRR</sub>	_	4	_	μS

Typical values are based on characterization data at V<sub>DD</sub> = 3.0V, 25°C unless otherwise stated.

 $<sup>^5</sup>$  Timing is shown with respect to 20%  $\rm V_{DD}$  and 80%  $\rm V_{DD}$  levels. Temperature range  $-40^{\circ}\rm C$  to 85°C.

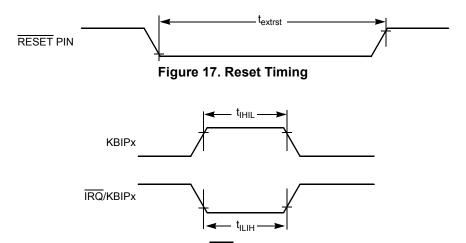


Figure 18. IRQ/KBIPx Timing

This is the shortest pulse that is guaranteed to be recognized as a reset or interrupt pin request. Shorter pulses are not guaranteed to override reset requests from internal sources.

To enter BDM mode following a POR, BKGD/MS should be held low during the power-up and for a hold time of t<sub>MSH</sub> after V<sub>DD</sub> rises above V<sub>LVD</sub>.

<sup>&</sup>lt;sup>4</sup> This is the minimum pulse width that is guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In stop mode, the synchronizer is bypassed so shorter pulses can be recognized in that case.

### 3.10.2 TPM Module Timing

Synchronizer circuits determine the shortest input pulses that can be recognized or the fastest clock that can be used as the optional external source to the timer counter. These synchronizers operate from the current bus rate clock.

**Table 14. TPM Input Timing** 

No.	С	Function	Symbol	Min	Max	Unit
1	D	External clock frequency	f <sub>TCLK</sub>	0	f <sub>Bus</sub> /4	Hz
2	D	External clock period	t <sub>TCLK</sub>	4	_	t <sub>cyc</sub>
3	D	External clock high time	t <sub>clkh</sub>	1.5	_	t <sub>cyc</sub>
4	D	External clock low time	t <sub>clkl</sub>	1.5	_	t <sub>cyc</sub>
5	D	Input capture pulse width	t <sub>ICPW</sub>	1.5	_	t <sub>cyc</sub>

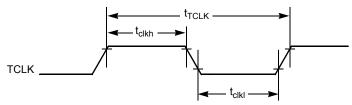


Figure 19. Timer External Clock

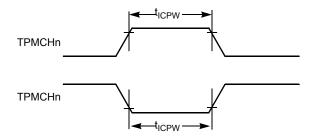


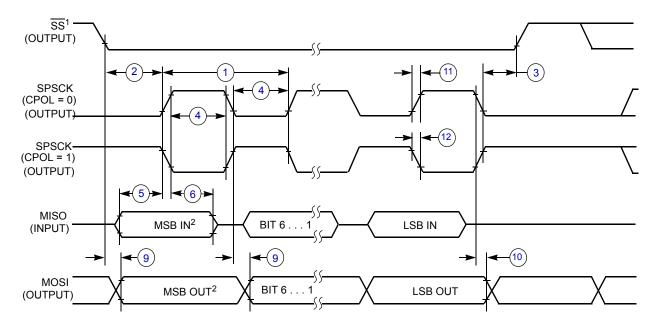
Figure 20. Timer Input Capture Pulse

### 3.10.3 SPI Timing

Table 15 and Figure 21 through Figure 24 describe the timing requirements for the SPI system.

Table 15. SPI Timing

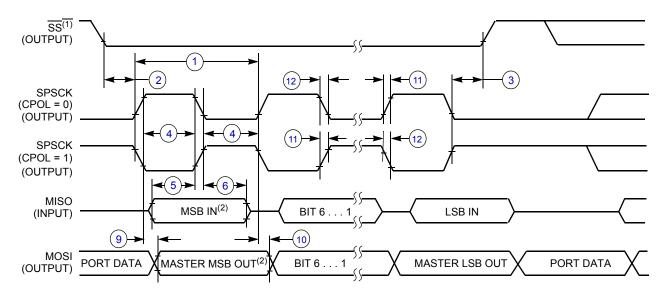
No.	С	Function	Symbol	Min	Max	Unit
_	D	Operating frequency Master Slave	f <sub>op</sub>	f <sub>Bus</sub> /2048	f <sub>Bus</sub> /2 f <sub>Bus</sub> /4	Hz Hz
1	D	SPSCK period Master Slave	t <sub>SPSCK</sub>	2 4	2048 —	t <sub>cyc</sub> t <sub>cyc</sub>
2	D	Enable lead time Master Slave	t <sub>Lead</sub>	1/2 1		t <sub>SPSCK</sub>
3	D	Enable lag time Master Slave	t <sub>Lag</sub>	1/2 1		t <sub>SPSCK</sub>
4	D	Clock (SPSCK) high or low time Master Slave	twspsck	t <sub>cyc</sub> - 30 t <sub>cyc</sub> - 30	1024 t <sub>cyc</sub>	ns ns
5	D	Data setup time (inputs) Master Slave	t <sub>SU</sub>	15 15		ns ns
6	D	Data hold time (inputs) Master Slave	t <sub>HI</sub>	0 25		ns ns
7	D	Slave access time	t <sub>a</sub>	_	1	t <sub>cyc</sub>
8	D	Slave MISO disable time	t <sub>dis</sub>	_	1	t <sub>cyc</sub>
9	D	Data valid (after SPSCK edge) Master Slave	t <sub>v</sub>		25 25	ns ns
10	D	Data hold time (outputs) Master Slave	t <sub>HO</sub>	0 0		ns ns
11	D	Rise time Input Output	t <sub>RI</sub>	_	t <sub>cyc</sub> – 25 25	ns ns
12	D	Fall time Input Output	t <sub>FI</sub>	_	t <sub>cyc</sub> – 25 25	ns ns



#### NOTES:

- 1.  $\overline{SS}$  output mode (DDS7 = 1, SSOE = 1).
- 2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

Figure 21. SPI Master Timing (CPHA = 0)

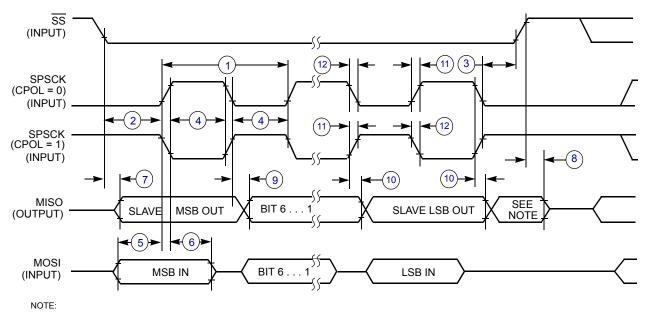


#### NOTES:

- 1.  $\overline{SS}$  output mode (DDS7 = 1, SSOE = 1).
- 2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

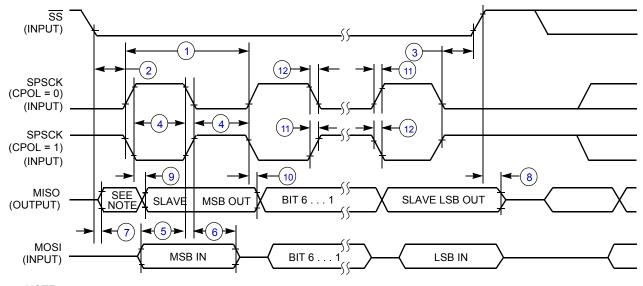
Figure 22. SPI Master Timing (CPHA =1)

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1. Not defined but normally MSB of character just received

Figure 23. SPI Slave Timing (CPHA = 0)



NOTE:

1. Not defined but normally LSB of character just received

Figure 24. SPI Slave Timing (CPHA = 1)

### 3.11 Analog Comparator (ACMP) Electricals

**Table 16. Analog Comparator Electrical Specifications** 

С	Characteristic	Symbol	Min	Typical	Max	Unit
D	Supply voltage	$V_{DD}$	1.80	_	3.6	V
С	Supply current (active)	I <sub>DDAC</sub>	_	20	35	μΑ
D	Analog input voltage	V <sub>AIN</sub>	$V_{SS} - 0.3$		$V_{DD}$	V
С	Analog input offset voltage	V <sub>AIO</sub>		20	40	mV
С	Analog comparator hysteresis	V <sub>H</sub>	3.0	9.0	15.0	mV
Р	Analog input leakage current	I <sub>ALKG</sub>	_		1.0	μА
С	Analog comparator initialization delay	t <sub>AINIT</sub>	_	_	1.0	μS

#### 3.12 ADC Characteristics

**Table 17. 12-bit ADC Operating Conditions** 

С	Characteristic	Conditions	Symb	Min	Typ <sup>1</sup>	Max	Unit	Comment
D	Supply voltage	Absolute	$V_{DDAD}$	1.8	_	3.6	V	
		Delta to V <sub>DD</sub> (V <sub>DD</sub> -V <sub>DDAD</sub> ) <sup>2</sup>	$\Delta V_{DDAD}$	-100	0	+100	mV	
D	Ground voltage	Delta to V <sub>SS</sub> (V <sub>SS</sub> -V <sub>SSAD</sub> ) <sup>2</sup>	$\Delta V_{SSAD}$	-100	0	+100	mV	
D	Ref Voltage High		$V_{REFH}$	1.8	$V_{DDAD}$	$V_{DDAD}$	V	
D	Ref Voltage Low		V <sub>REFL</sub>	V <sub>SSAD</sub>	V <sub>SSAD</sub>	V <sub>SSAD</sub>	V	
D	Input Voltage		$V_{ADIN}$	V <sub>REFL</sub>	_	V <sub>REFH</sub>	V	
С	Input Capacitance		C <sub>ADIN</sub>	_	4.5	5.5	pF	
С	Input Resistance		R <sub>ADIN</sub>	_	5	7	kΩ	
	Analog Source Resistance	12 bit mode f <sub>ADCK</sub> > 4MHz f <sub>ADCK</sub> < 4MHz	R <sub>AS</sub>	_	_	2 5		External to MCU
С		10 bit mode f <sub>ADCK</sub> > 4MHz f <sub>ADCK</sub> < 4MHz		_	_	5 10	kΩ	
		8 bit mode (all valid f <sub>ADCK</sub> )		_	_	10		
D		High Speed (ADLPC=0)	f <sub>ADCK</sub>	0.4	_	8.0	MHz	
	Clock Freq.	Low Power (ADLPC=1)		0.4	_	4.0	1011 12	

Typical values assume V<sub>DDAD</sub> = 3.0V, Temp = 25°C, f<sub>ADCK</sub>=1.0MHz unless otherwise stated. Typical values are for reference only and are not tested in production.

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<sup>&</sup>lt;sup>2</sup> DC potential difference.

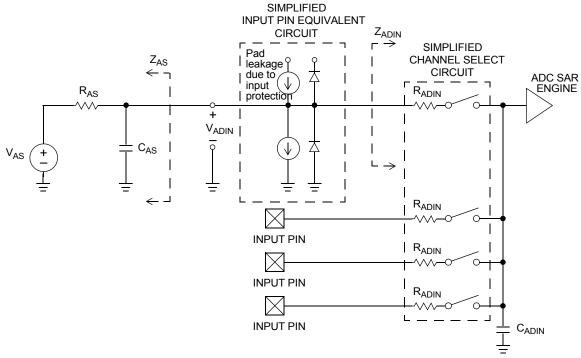


Figure 25. ADC Input Impedance Equivalency Diagram

Table 18. 12-bit ADC Characteristics ( $V_{REFH} = V_{DDAD}$ ,  $V_{REFL} = V_{SSAD}$ )

Characteristic	Conditions	С	Symb	Min	Typ <sup>1</sup>	Max	Unit	Comment
Supply Current ADLPC=1 ADLSMP=1 ADCO=1		Т	I <sub>DDAD</sub>	_	120	_	μА	
Supply Current ADLPC=1 ADLSMP=0 ADCO=1		Т	I <sub>DDAD</sub>	_	202	_	μА	
Supply Current ADLPC=0 ADLSMP=1 ADCO=1		Т	I <sub>DDAD</sub>	_	288	_	μА	
Supply Current ADLPC=0 ADLSMP=0 ADCO=1		D	I <sub>DDAD</sub>	_	0.532	1	mA	
Supply Current	Stop, Reset, Module Off	Р	I <sub>DDAD</sub>	_	0.007	0.8	μΑ	
ADC	High Speed (ADLPC=0)	Р	f <sub>ADACK</sub>	2	3.3	5	N/1.1-	t <sub>ADACK</sub> = 1/f <sub>ADACK</sub>
Asynchronous Clock Source	Low Power (ADLPC=1)	Р		1.25	2	3.3	MHz	

Table 18. 12-bit ADC Characteristics ( $V_{REFH} = V_{DDAD}$ ,  $V_{REFL} = V_{SSAD}$ ) (continued)

Characteristic	Conditions	С	Symb	Min	Typ <sup>1</sup>	Max	Unit	Comment	
Conversion Time	Short Sample (ADLSMP=0)	Р	t <sub>ADC</sub>	_	20	_	ADCK	See the ADC	
(Including sample time)	Long Sample (ADLSMP=1)	С		_	40	_	cycles	chapter in the MC9S08QE128 Reference Manual for conversion time variances	
Sample Time	Short Sample (ADLSMP=0)	Р	t <sub>ADS</sub>	_	3.5	_	ADCK		
	Long Sample (ADLSMP=1)	С			23.5	_	cycles		
Total Unadjusted	12 bit mode	Т	E <sub>TUE</sub>	_	±3.0	_	LSB <sup>2</sup>	Includes Quantization	
Error	10 bit mode	Р		_	±1	±2.5			
	8 bit mode	Т		_	±0.5	±1.0			
Differential	12 bit mode	Т	DNL	_	±1.75	_	LSB <sup>2</sup>		
Non-Linearity	10 bit mode <sup>3</sup>	Р		_	±0.5	±1.0			
	8 bit mode <sup>3</sup>	Т		_	±0.3	±0.5			
Integral	12 bit mode	Т	INL	_	±1.5	_	LSB <sup>2</sup>		
Non-Linearity	10 bit mode	Т		_	±0.5	±1.0			
	8 bit mode	Т		_	±0.3	±0.5			
Zero-Scale Error	12 bit mode	Т	E <sub>ZS</sub>	_	±1.5	_	LSB <sup>2</sup>	V <sub>ADIN</sub> = V <sub>SSAD</sub>	
	10 bit mode	Р		_	±0.5	±1.5			
	8 bit mode	Т			±0.5	±0.5			
Full-Scale Error	12 bit mode	Т	E <sub>FS</sub>	_	±1.0	_	LSB <sup>2</sup>	V <sub>ADIN</sub> = V <sub>DDAD</sub>	
	10 bit mode	Р		_	±0.5	±1			
	8 bit mode	Т			±0.5	±0.5			
Quantization	12 bit mode	D	EQ	_	-1 to 0	_	LSB <sup>2</sup>		
Error	10 bit mode			_	_	±0.5			
	8 bit mode			_	_	±0.5			
Input Leakage	12 bit mode	D	E <sub>IL</sub>	_	±2	_	LSB <sup>2</sup>	Pad leakage <sup>4</sup> * R <sub>AS</sub>	
Error	10 bit mode			_	±0.2	±4			
	8 bit mode			_	±0.1	±1.2			
Temp Sensor	-40°C to 25°C	D	m	_	1.646	_	mV/°C		
Slope	25°C to 85°C			_	1.769	_			
Temp Sensor Voltage	25°C	D	V <sub>TEMP25</sub>	_	701.2	_	mV		

Typical values assume V<sub>DDAD</sub> = 3.0V, Temp = 25°C, f<sub>ADCK</sub>=1.0MHz unless otherwise stated. Typical values are for reference only and are not tested in production.

 $<sup>^{2}</sup>$  1 LSB =  $(V_{REFH} - V_{REFL})/2^{N}$ 

<sup>&</sup>lt;sup>3</sup> Monotonicity and No-Missing-Codes guaranteed in 10 bit and 8 bit modes

<sup>&</sup>lt;sup>4</sup> Based on input pad leakage current. Refer to pad electricals.

### 3.13 Flash Specifications

This section provides details about program/erase times and program-erase endurance for the flash memory.

Program and erase operations do not require any special power sources other than the normal  $V_{DD}$  supply. For more detailed information about program/erase operations, see the Memory section of the MC9S08QE128 Reference Manual.

**Table 19. Flash Characteristics** 

С	Characteristic	Symbol	Min	Typical	Max	Unit
D	Supply voltage for program/erase -40°C to 85°C	V <sub>prog/erase</sub>	1.8		3.6	V
D	Supply voltage for read operation	V <sub>Read</sub>	1.8		3.6	V
D	Internal FCLK frequency <sup>1</sup>	f <sub>FCLK</sub>	150		200	kHz
D	Internal FCLK period (1/FCLK)	t <sub>Fcyc</sub>	5		6.67	μS
Р	Byte program time (random location) <sup>(2)</sup>	t <sub>prog</sub>	9			t <sub>Fcyc</sub>
Р	Byte program time (burst mode) <sup>(2)</sup>	t <sub>Burst</sub>	4		t <sub>Fcyc</sub>	
Р	Page erase time <sup>2</sup>	t <sub>Page</sub>	4000		t <sub>Fcyc</sub>	
Р	Mass erase time <sup>(2)</sup>	t <sub>Mass</sub>	20,000		t <sub>Fcyc</sub>	
	Byte program current <sup>3</sup>	R <sub>IDDBP</sub>	_	4	_	mA
	Page erase current <sup>3</sup>	R <sub>IDDPE</sub>	_	6	_	mA
С	Program/erase endurance <sup>4</sup> $T_L$ to $T_H = -40^{\circ}C$ to + 85°C $T = 25^{\circ}C$		10,000 —	 100,000		cycles
С	Data retention <sup>5</sup>	t <sub>D_ret</sub>	15	100	_	years

The frequency of this clock is controlled by a software setting.

<sup>&</sup>lt;sup>2</sup> These values are hardware state machine controlled. User code does not need to count cycles. This information supplied for calculating approximate time to program and erase.

<sup>&</sup>lt;sup>3</sup> The program and erase currents are additional to the standard run  $I_{DD}$ . These values are measured at room temperatures with  $V_{DD} = 3.0 \text{ V}$ , bus frequency = 4.0 MHz.

Typical endurance for flash was evaluated for this product family on the HC9S12Dx64. For additional information on how Freescale defines typical endurance, please refer to Engineering Bulletin EB619, Typical Endurance for Nonvolatile Memory

Typical data retention values are based on intrinsic capability of the technology measured at high temperature and de-rated to 25°C using the Arrhenius equation. For additional information on how Freescale defines typical data retention, please refer to Engineering Bulletin EB618, Typical Data Retention for Nonvolatile Memory.

## 4 Ordering Information

This section contains ordering information for MC9S08QE128, MC9S08QE96, and MC9S08QE64 devices.

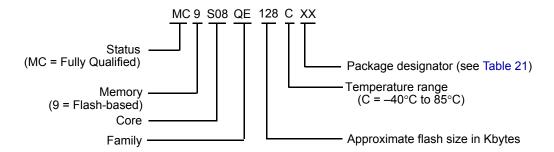
**Table 20. Ordering Information** 

Freescale Part Number <sup>1</sup>	Mer	nory	Temperature range (°C)	Package <sup>2</sup>	
Freescale Fait Number	Flash	RAM	- remperature range ( C)		
MC9S08QE128CLK			-40 to +85	80 LQFP	
MC9S08QE128CLH	128K	8K	-40 to +85	64 LQFP	
MC9S08QE128CFT	IZON	or.	-40 to +85	48 QFN	
MC9S08QE128CLD			-40 to +85	44 LQFP	
MC9S08QE96CLK			-40 to +85	80 LQFP	
MC9S08QE96CLH	96K	6K	-40 to +85	64 LQFP	
MC9S08QE96CFT	901		-40 to +85	48 QFN	
MC9S08QE96CLD			-40 to +85	44 QFP	
MC9S08QE64CLH			-40 to +85	64 LQFP	
MC9S08QE64CFT	64K	4K	-40 to +85	48 QFN	
MC9S08QE64CLD	041		-40 to +85	44 QFP	
MC9S08QE64CLC			-40 to +85	32 LQFP	

<sup>&</sup>lt;sup>1</sup> See the reference manual, MC9S08QE128RM, for a complete description of modules included on each device.

### 4.1 Device Numbering System

Example of the device numbering system:



## 5 Package Information

The below table details the various packages available.

**Table 21. Package Descriptions** 

Pin Count	Package Type	Abbreviation	Designator	Case No.	Document No.
80	Low Quad Flat Package	LQFP	LK	917A	98ASS23237W
64	Low Quad Flat Package	LQFP	LH	840F	98ASS23234W
48	Quad Flat No-Leads	QFN	FT	1314	98ARH99048A
44	Low Quad Flat Package	LQFP	LD	824D	98ASS23225W
32	Low Quad Flat Package	LQFP	LC	873A	98ASH70029A

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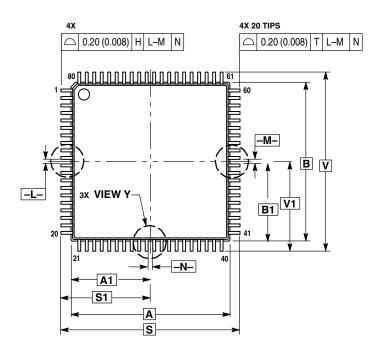
<sup>&</sup>lt;sup>2</sup> See Table 21 for package information.

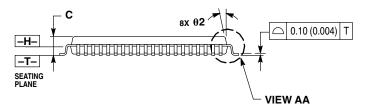
### 5.1 Mechanical Drawings

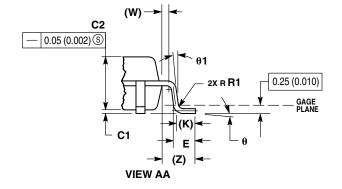
The following pages are mechanical drawings for the packages described in Table 21. For the latest available drawings please visit our web site (http://www.freescale.com) and enter the package's document number into the keyword search box.

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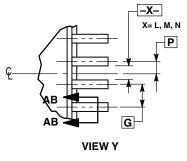
#### **Package Information**

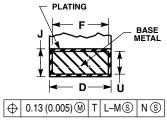






**DATE 09/21/95 CASE 917A-02 ISSUE C** 





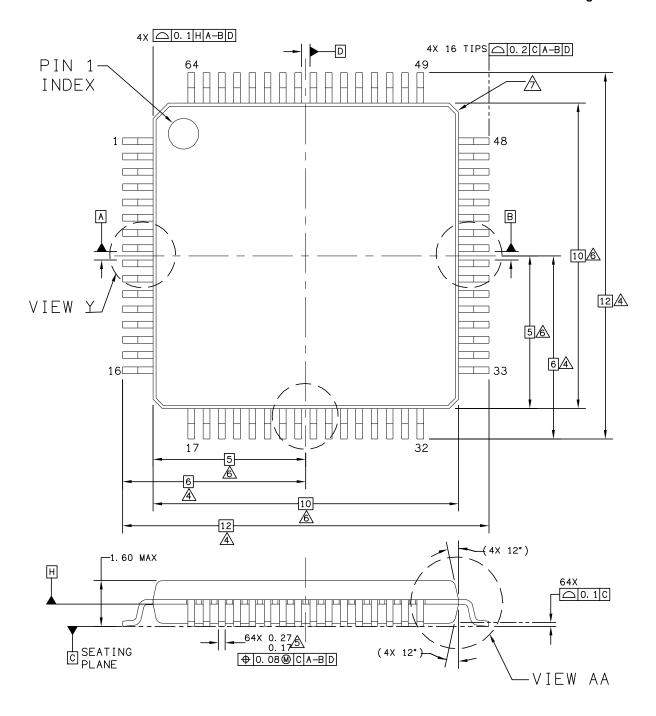
**SECTION AB-AB** ROTATED 90 ° CLOCKWISE

- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.
- DATUM PLANE -H- IS LOCATED AT BOTTOM OF LEAD AND IS COINCIDENT WITH THE LEAD WHERE THE LEAD EXITS THE PLASTIC BODY AT
- THE BOTTOM OF THE PARTING LINE.
  DATUMS -L-, -M- AND -N- TO BE DETERMINED
  AT DATUM PLANE -H-.
- DIMENSIONS S AND V TO BE DETERMINED AT SEATING PLANE -T-.
  6. DIMENSIONS A AND B DO NOT INCLUDE MOLD
- PROTRUSION. ALLOWABLE PROTRUSION IS 0.250 (0.010) PER SIDE. DIMENSIONS A AND B DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE -H-.
- DIMENSION D DOES NOT INCLUDE DAMBAR
   PROTRUSION. DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED 0.460 (0.018), MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD OR PROTRUSION 0.07 (0.003).

	MILLIN	IETERS	INCHES			
DIM	MIN	MAX	MIN	MAX		
Α	14.00	BSC	0.551 BSC			
A1	7.00	BSC	0.276	0.276 BSC		
В	14.00	BSC	0.551 BSC			
B1	7.00	BSC	0.276 BSC			
С		1.60		0.063		
C1	0.04	0.24	0.002	0.009		
C2	1.30	1.50	0.051	0.059		
D	0.22	0.38	0.009	0.015		
E	0.40	0.75	0.016	0.030		
F	0.17	0.33	0.007	0.013		
G	0.65	BSC	0.026 BSC			
J	0.09	0.27	0.004	0.011		
K	0.50	REF	0.020	REF		
Р	0.325	BSC	0.013 REF			
R1	0.10	0.20	0.004	0.008		
S	16.00	BSC	0.630 BSC			
S1	8.00	BSC	0.315 BSC			
U	0.09	0.16	0.004	0.006		
٧	16.00	BSC	0.630 BSC			
V1	8.00 BSC		0.315 BSC			
W	0.20 REF		0.008 REF			
Z		REF		REF		
0	0 °	10°	0 °	10°		
01	0°		0°			
02	9°	14°	9°	14°		

Figure 26. 80-pin LQFP Package Drawing (Case 917A, Doc #98ASS23237W)

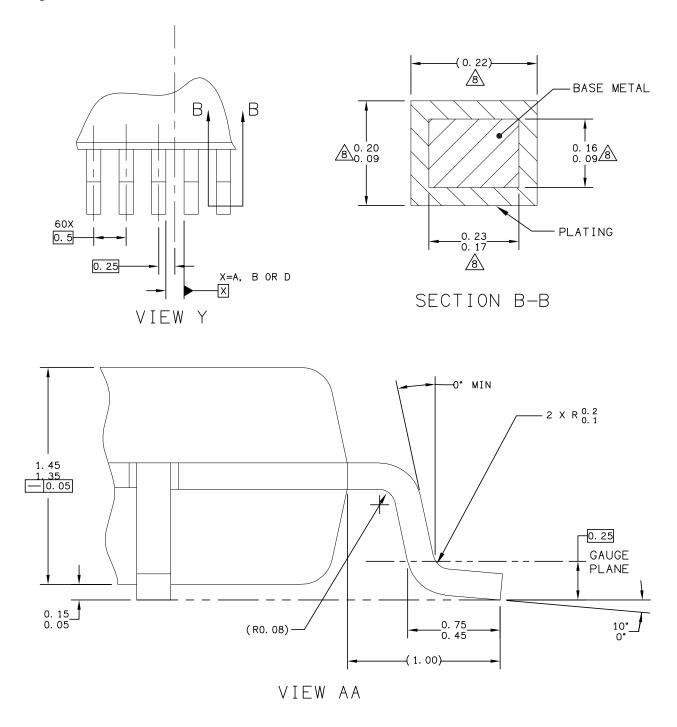
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10 X 10 X 1. 4 PKG,		DOCUMENT NO	): 98ASS23234W	REV: D
		CASE NUMBER	R: 840F-02	06 APR 2005
		STANDARD: JE	IDEC MS-026 BCD	

Figure 27. 64-pin LQFP Package Drawing (Case 840F, Doc #98ASS23234W), Sheet 1 of 3

# **Package Information**



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TITLE: 64LD LQFP, 10 X 10 X 1.4 PKG, 0.5 PITCH, CASE OUTLINE		DOCUMENT NO	): 98ASS23234W	REV: D
		CASE NUMBER	R: 840F-02	06 APR 2005
		STANDARD: JE	DEC MS-026 BCD	

Figure 28. 64-pin LQFP Package Drawing (Case 840F, Doc #98ASS23234W), Sheet 2 of 3

MC9S08QE128 Series Data Sheet, Rev. 7

#### NOTES:

- 1. DIMENSIONS ARE IN MILLIMETERS.
- 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- 3. DATUMS A, B AND D TO BE DETERMINED AT DATUM PLANE H.

A DIMENSIONS TO BE DETERMINED AT SEATING PLANE C.

THIS DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED THE UPPER LIMIT BY MORE THAN 0.08 mm AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD SHALL NOT BE LESS THAN 0.07 mm.

THIS DIMENSION DOES NOT INCLUDE MOLD PROTRUSION. ALLOWABLE
PROTRUSION IS 0.25 mm PER SIDE. THIS DIMENSION IS MAXIMUM PLASTIC BODY
SIZE DIMENSION INCLUDING MOLD MISMATCH.

A. EXACT SHAPE OF EACH CORNER IS OPTIONAL.

8. THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.1 mm AND 0.25 mm FROM THE LEAD TIP.

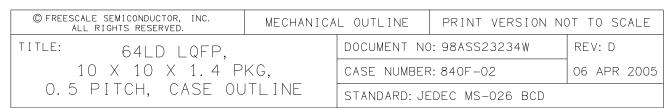
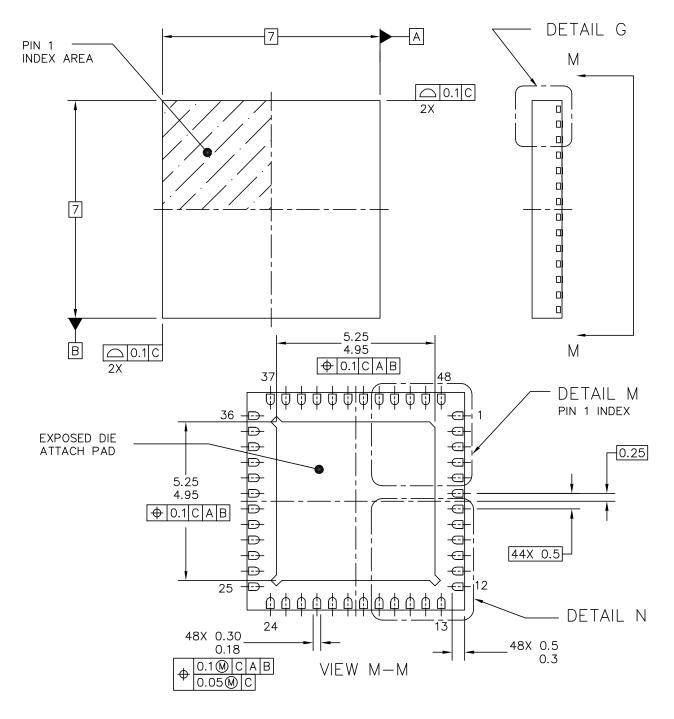


Figure 29. 64-pin LQFP Package Drawing (Case 840F, Doc #98ASS23234W), Sheet 3 of 3

MC9S08QE128 Series Data Sheet, Rev. 7

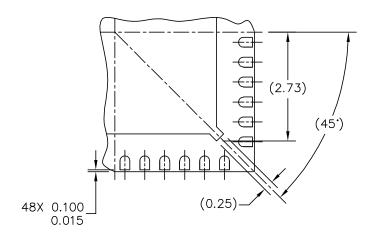
# **Package Information**

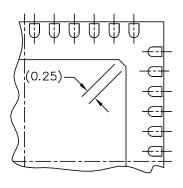


© FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED.	MECHANICAL OUTLINE		PRINT VERSION NO	T TO SCALE
TITLE: THERMALLY ENHANCED	QUAD	DOCUMENT NO	): 98ARH99048A	REV: F
FLAT NON-LEADED PACKAGE (QFN)		CASE NUMBER	R: 1314–05	05 DEC 2005
48 TERMINAL, 0.5 PITCH (7	X / X 1)	STANDARD: JE	DEC-MO-220 VKKD-2	2

Figure 30. 48-pin QFN Package Drawing (Case 1314, Doc #98ARH99048A), Sheet 1 of 3

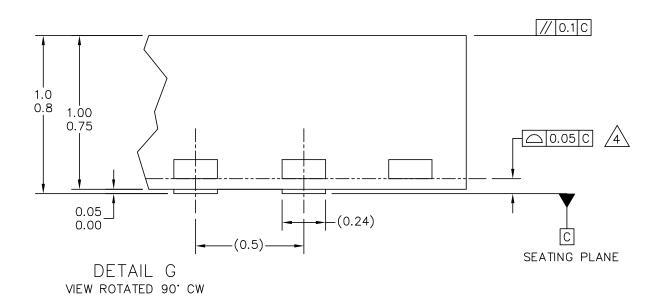
MC9S08QE128 Series Data Sheet, Rev. 7





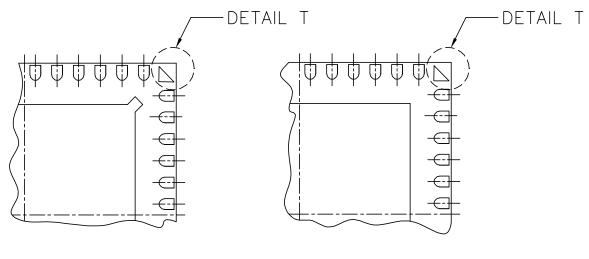
DETAIL N
PREFERRED CORNER CONFIGURATION

DETAIL M
PREFERED PIN 1 BACKSIDE IDENTIFIER



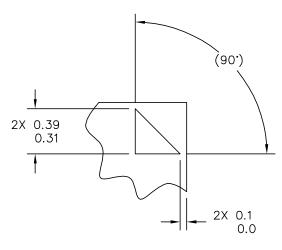
© FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED.	MECHANICA	L OUTLINE	PRINT VERSION NO	T TO SCALE
TITLE: THERMALLY ENHANCED	QUAD	DOCUMENT NO	): 98ARH99048A	REV: F
FLAT NON-LEADED PACKA	` ,	CASE NUMBER	2: 1314–05	05 DEC 2005
48 TERMINAL, 0.5 PITCH (7	/ X / X 1)	STANDARD: JE	DEC-MO-220 VKKD-2	2

Figure 31. 48-pin QFN Package Drawing (Case 1314, Doc #98ARH99048A), Sheet 2 of 3



DETAIL M
PIN 1 BACKSIDE IDENTIFIER OPTION

DETAIL M
PIN 1 BACKSIDE IDENTIFIER OPTION



DETAIL T

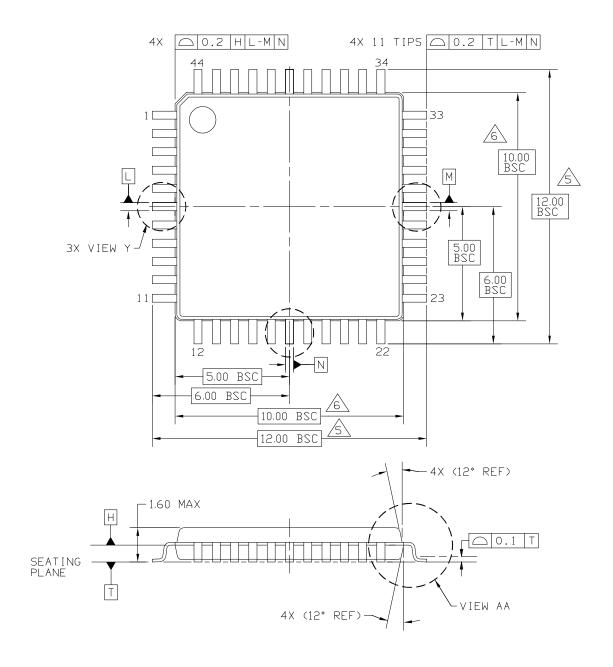
NOTES:

- 1. DIMENSIONS ARE IN MILLIMETERS.
- 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
- 3. THE COMPLETE JEDEC DESIGNATOR FOR THIS PACKAGE IS: HF-PQFN.
- 4.\ COPLANARITY APPLIES TO LEADS, CORNER LEADS, AND DIE ATTACH PAD.
- 5. MIN METAL GAP SHOULD BE 0.2MM.

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TITLE: THERMALLY ENHANCED QUAD		DOCUMENT NO	): 98ARH99048A	REV: F
FLAT NON-LEADED PACKAGE (QFN)		CASE NUMBER: 1314-05 05 DEC 200		05 DEC 2005
48 TERMINAL, 0.5 PITCH (7	7 X 7 X 1)	STANDARD: JE	DEC-MO-220 VKKD-2	2

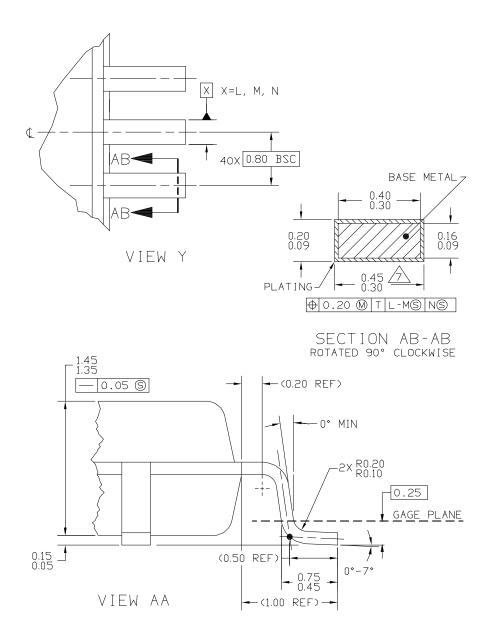
Figure 32. 48-pin QFN Package Drawing (Case 1314, Doc #98ARH99048A), Sheet 3 of 3

# MC9S08QE128 Series Data Sheet, Rev. 7



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TITLE:  44 LD LQFP,  10 X 10 PKG, 0.8 PITCH, 1.4 THICK		DOCUMENT NO	]: 98ASS23225W	REV: D
		CASE NUMBER	R: 824D-02	26 FEB 2007
		STANDARD: JE	DEC MS-026-BCB	

Figure 33. 44-pin LQFP Package Drawing (Case 824D, Doc #98ASS23225W), Sheet 1 of 3



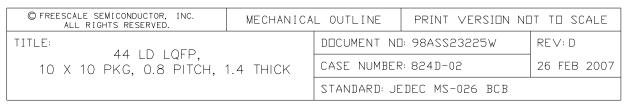


Figure 34. 44-pin LQFP Package Drawing (Case 824D, Doc #98ASS23225W), Sheet 2 of 3

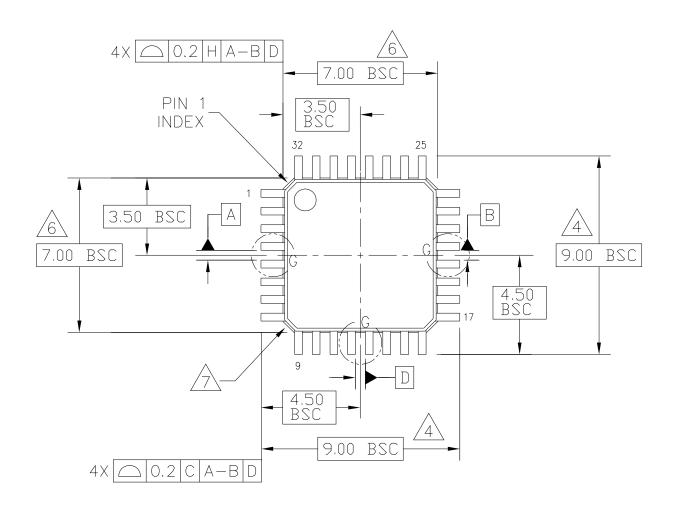
#### NOTES:

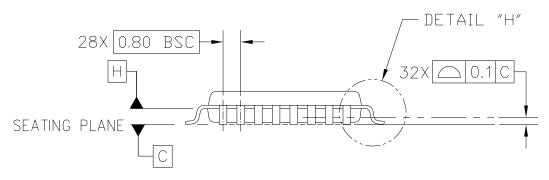
- 1. DIMENSIONS AND TOLERANCING PER ASME Y14,5M-1994.
- 2. CONTROLLING DIMENSION: MILLIMETER
- 3. DATUM PLANE H IS LOCATED AT BOTTOM OF LEAD AND IS COINCIDENT WITH THE LEAD WHERE THE LEAD EXITS THE PLASTIC BODY AT THE BOTTOM OF THE PARTING LINE.
- 4. DATUMS L, M AND N TO BE DETERMINED AT DATUM PLANE H.
- 5. DIMENSIONS TO BE DETERMINED AT SEATING PLANE T.
- DIMENSIONS DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25 PER SIDE. DIMENSIONS DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE H.
- DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. DAMBAR PROTRUSION SHALL NOT CAUSE THE DIMENSION TO EXCEED 0.53. MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD OR PROTRUSION 0.07.

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	TITLE:  44 LD LQFP,  10 X 10 PKG, 0.8 PITCH, 1.4 THICK		DOCUMENT NO	]: 98ASS23225W	REV: D
			CASE NUMBER	R: 824D-02	26 FEB 2007
			STANDARD: JE	IDEC MS-026 BCB	

Figure 35. 44-pin LQFP Package Drawing (Case 824D, Doc #98ASS23225W), Sheet 3 of 3

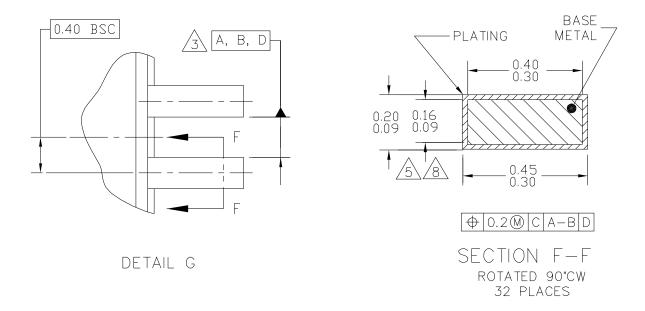
MC9S08QE128 Series Data Sheet, Rev. 7

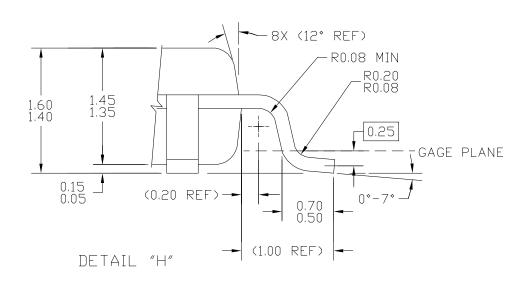




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TITLE:		DOCUMENT NO	1: 98ASH70029A	REV: D
LOW PROFILE QUAD FLAT PACK (LQFP) 32 LEAD, 0.8 PITCH (7 X 7 X 1.4)		CASE NUMBER	8: 873A-03	19 MAY 2005
		STANDARD: JE	IDEC MS-026 BBA	

Figure 36. 32-pin LQFP Package Drawing (Case 873A, Doc #98ASH70029A), Sheet 1 of 3





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TITLE:  LOW PROFILE QUAD FLAT PACK (LQFP)  32 LEAD, 0.8 PITCH (7 X 7 X 1.4)		DOCUMENT NO	1: 98ASH70029A	RE∨: D
		CASE NUMBER	8: 873A-03	19 MAY 2005
		STANDARD: JE	DEC MS-026 BBA	

Figure 37. 32-pin LQFP Package Drawing (Case 873A, Doc #98ASH70029A), Sheet 2 of 3

## **Package Information**

### NOTES:

- 1. DIMENSIONS ARE IN MILLIMETERS.
- 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5-1994.

 $\overline{\mathfrak{A}}$  datums A, B, and d to be determined at datum plane H.

 $\overline{4}$  dimensions to be determined at seating plane datum c.

DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED THE MAXIMUM DIMENSION BY MORE THAN 0.08 MM. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD OR PROTRUSION: 0.07 MM.

6. DIMENSIONS DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25 MM PER SIDE. DIMENSIONS ARE MAXIMUM PLASTIC BODY SIZE DIMENSIONS INCLUDING MOLD MISMATCH.

2. EXACT SHAPE OF EACH CORNER IS OPTIONAL.

THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.1 MM AND 0.25 MM FROM THE LEAD TIP.

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LOW PROFILE QUAD FLAT PACK (LQFP)		DOCUMENT NO	1: 98ASH70029A	REV: D
		CASE NUMBER	2: 873A-03	19 MAY 2005
		STANDARD: JE	DEC MS-026 BBA	

Figure 38. 32-pin LQFP Package Drawing (Case 873A, Doc #98ASH70029A), Sheet 3 of 3

# MC9S08QE128 Series Data Sheet, Rev. 7

# 6 Product Documentation

Find the most current versions of all documents at: http://www.freescale.com

Reference Manual (MC9S08QE128RM)

Contains extensive product information including modes of operation, memory, resets and interrupts, register definition, port pins, CPU, and all module information.

# 7 Revision History

To provide the most up-to-date information, the revision of our documents on the World Wide Web are the most current. Your printed copy may be an earlier revision. To verify you have the latest information available, refer to:

http://www.freescale.com

The following revision history table summarizes changes contained in this document.

**Table 22. Revision History** 

Revision	Date	Description of Changes
4	9 Nov 2007	Replaced 44 QFP package with 44 LQFP package.
		Changed ACMP electricals, V <sub>AIO</sub> specification's test category from P to C.
5	28 May 2008	Updated the tables Thermal Characteristics, DC Characteristics, Supply Current Characteristics, XOSC and ICS Specifications (Temperature Range = -40 to 85°C Ambient), ICS Frequency Specifications (Temperature Range = -40 to 85°C Ambient), Control Timing, and Analog Comparator Electrical Specifications, 12-bit ADC Characteristics (VREFH = VDDAD, VREFL = VSSAD)  Updated the figures Typical Run IDD for FBE and FEI, IDD vs. VDD (ACMP and ADC off, All Other Modules Enabled), Deviation of DCO Output from Trimmed Frequency (50.33 MHz, 3.0 V), and Deviation of DCO Output from Trimmed Frequency (50.33 MHz, 25°C)
6	24 Jun 2008	Updated the table Thermal Characteristics Updated the row corresponding to Num 18 in the table DC Characteristics Updated the tables MC9S08QE128 Series Features by MCU and Package, DC Characteristics, Supply Current Characteristics, Thermal Characteristics, Control Timing, and Ordering Information Updated the figures Typical Run IDD for FBE and FEI, IDD vs. VDD (ADC off, All Other Modules Enabled), Deviation of DCO Output Across Temperature at VDD = 3.0 V, and Deviation of DCO Output Across VDD at 25×C
7	2 Oct 2008	Updated the Stop2 and Stop3 mode supply current in the Supply Current Characteristics table. Replaced the stop mode adders section from the Supply Current Characteristics with its own Stop Mode Adders table with new specifications.

MC9S08QE128 Series Data Sheet, Rev. 7

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